

# 40CTQ045 40CTQ045S 40CTQ045-1

#### Technical Data Data Sheet N0614, Rev. A

RoHS 🗭

# 40CTQ045 /40CTQ045S /40CTQ045-1 SCHOTTKY RECTIFIER

### Features

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

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### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=129°C, In DC	20(Per Leg) 40(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	420	А

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# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.52	0.53	V
(Per Leg)*	V <sub>F2</sub>	@ 20A, Pulse, T <sub>J</sub> = 125 °C	0.47	0.48	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>J</sub> = 25 °C	0.05	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	37	115	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	928	2800	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

### **Thermal-Mechanical Specifications:**

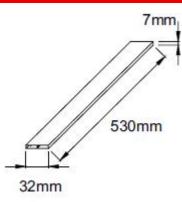
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0JC</sub>	DC operation	2.0	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0JS</sub>	DC operation	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

### **Tube Specification**

Device	Package	Weight	Shipping
40CTQ045	TO-220AB	1.8g	50pcs / tube
40CTQ045S	D <sup>2</sup> PAK	1.85g	800pcs / reel
40CTQ045-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Tube Specification(TO-220AB/TO-262)



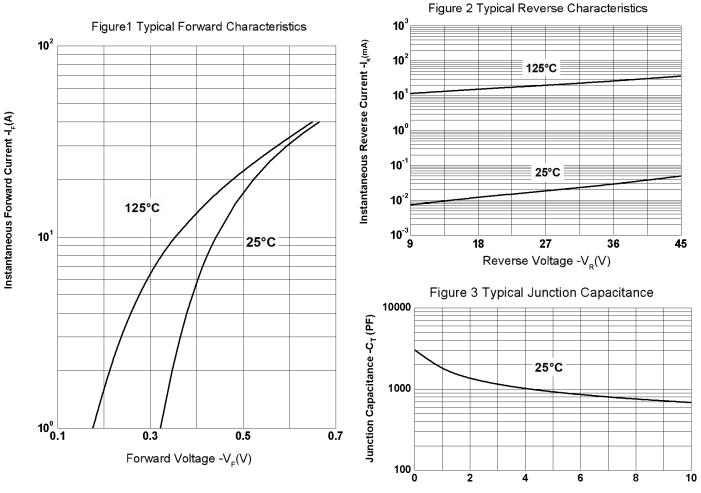


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### **Ratings and Characteristics Curves**



Reverse Voltage -V<sub>R</sub>(V)



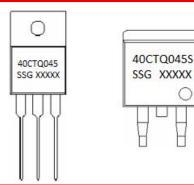
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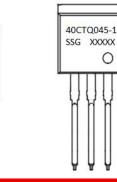
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# **Marking Diagram**





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#### Where XXXXX is YYWWL

- = Forward Current (40A)
- = Configuration
- = Device Type
- = Reverse Voltage (45V) = Package type
- = SSG
- = Year

40

C TQ

45

S/-1

SSG

YΥ

WW

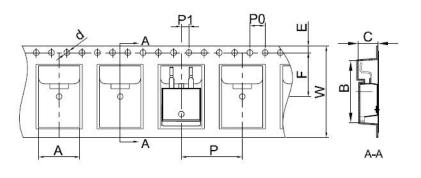
L

= Week = Lot Number

Cautions: Molding resin

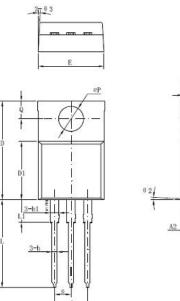
Epoxy resin UL:94V-0

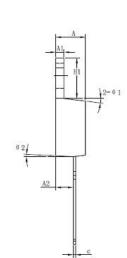
### **Carrier Tape Specification D<sup>2</sup>PAK**



Symbol	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

#### **Mechanical Dimensions TO-220AB**





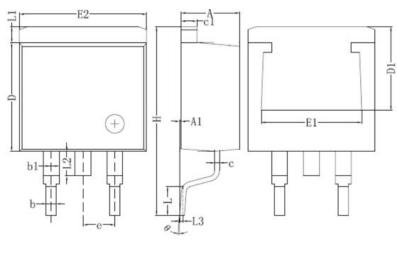
Symbol	Dimensions in millimeters			
	Min	Typical	Max	
A	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ΦΡ	-	3.56	-	
Q	2.54	-	3.43	

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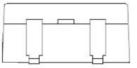


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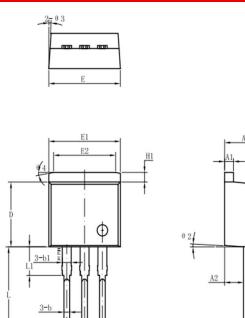
# Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
A	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.54	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	



### **Mechanical Dimensions TO-262**



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
В	1.22	1.37	1.47	
b	0.71	0.81	0.96	
b1		1.27		
C	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
Θ1		5°		
Θ2		<b>4</b> °		
Θ3		4°		
Θ4		10°		

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